

# 3-Phase Brushless Motor Predriver with Digital Speed Control

## Overview

The LB1822 is a monolithic predriver IC for controlling three-phase brushless motors and has an on-chip digital speed control circuit. The LB1822 is ideally suited for driving the motor of laser beam printers, facsimiles, plain paper copiers, and so on.

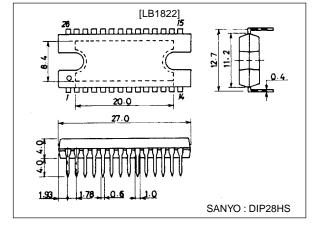
#### **Features**

- 30V withstand voltage and 30mA output current.
- Current limiter.
- Low-voltage protection circuit.
- Thermal shutdown circuit.
- Hall amp with hysteresis characteristic.
- Start/Stop terminals.
- Crystal osillator and divider.
- · Digital speed control circuit.
- · Lock detector.

## **Package Dimensions**

unit:mm

3147A-DIP28HS



# **Specifications**

## Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage 1	Vcc		30	V
Maximum supply voltage 2	V <sub>M</sub>		30	V
Output current	IO		30	mA
Allowable power dissipation1	Pd max1	Independent IC	3	W
Allowable power dissipation2	Pd max2	With infinte heat sink	20	W
Operating temperature	Topr		-20 to +80	°C
Storage temperature	Tstg		-55 to +150	°C

#### Allowable Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage1	Vcc		9.5 to 28	V
Supply voltage2	V <sub>M</sub>		5 to 28	V
Voltage regulator output current	I <sub>VH</sub>		0 to 20	mA
Comparator output current	losc		0 to 30	mA
Lock detector output current	ILD		0 to 20	mA

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# Electrical Characteristics at Ta = 25 $^{\circ}$ C, $V_{CC}$ = $V_{M}$ =24V

		I				
Parameter	Symbol	Conditions		Ratings		Unit
			min	typ	max	
Supply current 1	lcc1			33	50	mA
Supply current 2	l <sub>CC</sub> 2	Stop mode		3	5	mA
Output saturation voltage	V <sub>O</sub> sat1	I <sub>O</sub> =10mA		1.5	2.0	V
Output leak current	I <sub>O</sub> leak				100	μΑ
[Voltage regulator]						
Output voltage	VH	I <sub>VH</sub> =10mA	3.8	4.15	4.5	V
Voltage fluctuation	$\Delta V_{H1}$	V <sub>CC</sub> =9.5 to 28V		60	150	mV
Load fluctuation	ΔV <sub>H2</sub>	I <sub>VH</sub> =5 to 20V		60	150	mV
Temperature Coefficient				-2		mV/°C
[Hall amplifier]						
Input bias current	I <sub>НВ</sub>			1	4	μΑ
Common-mode input voltage	VICH		1.5		2.8	V
Hall input sensitivity			100			mVp-p
Hysteresis width	ΔV <sub>IN</sub>		24	33	42	mV
Low to high input voltage	VSLH		8	20	32	mV
High to low input voltage	V <sub>SHL</sub>		-25	-13	-1	mV
[Oscillator]	) SIIL	1	1 20		-	
High-level output voltage	V <sub>OH(CR)</sub>		2.9	3.2	3.5	V
Low-level output voltage	VOL(CR)		0.9	1.1	1.3	
Oscillation amplitude	VOL(CR)		1.8	2.1	2.4	V
Oscillation frequency	f	R=300kΩ, C=1500pF	1.0	18.5	2.7	kHz
Temperature coefficient	Δf	11-300ks2, 0-1300p1		0.1		%/°C
[Comparator]	ΔΙ			0.1		767 C
		1 20 4			4.5	
Output voltage	Vosc	I <sub>OSC</sub> =20mA			1.5	V
[Current limiter]		T	0.40	0.5		
Limiter1	V <sub>Rf1</sub>		0.42	0.5	0.6	V
Lmiter2	V <sub>Rf2</sub>		0.4	0.44	0.48	V
Thermal shutdown temperature	TSD	Design target	150	180		°C
Hysteresis width	ΔTSD			30		°C
Low-voltage protection voltage	V <sub>LVSD</sub>		7.5	8.1	8.7	V
Hysteresis width	∆VLVSD		0.45	0.6	0.75	V
[FG amplifier]						
Input offset voltage	V <sub>IO(FG)</sub>		-10		+10	mV
Input bias current	I <sub>B(FG)</sub>		-1		+1	μΑ
High-level output voltage	V <sub>OH(FG)</sub>	I <sub>FG</sub> =-2mA	5.6	6.2	6.8	V
Low-level output voltage	V <sub>OL(FG)</sub>	I <sub>FG</sub> =2mA		1	1.5	V
FG input sensitivity		10×Gain	5			mV
Schmitt width at next stage				16		mV
Operating frequency range					5	kHz
Open-loop voltage gain			60			dB
[Speed Discriminator]						
High-level output voltage	V <sub>OH(D)</sub>			4.7		V
Low-level output voltage	V <sub>OL(D)</sub>			0.3		V
Maximum clock frequency	JL(D)	Tj=100°C	1.05			MHz
Count pulses			2044	2046	2048	
[Integrator]		1	2011	_5.5	_0.0	
Input offset voltage	V <sub>IO(INT)</sub>		-10		10	mV
Input bias current	I <sub>B</sub> (INT)		-0.4		+0.4	μA
High-level output voltage	VOH(INT)		3.7	4.3	4.9	V
Low-level output voltage	VOL(INT)		3.7	0.8	1.2	V
Open-loop gain	*OL(IN1)		60	0.0	1.4	dB
Gain-bandwidth product			60	1.6		MHz
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Reference votlage			-5%	V5/2	+5%	V
5V supply	V5		4.6	5	5.4	V
[Lock detection]		1				
Low-level output voltage	V <sub>OL(LD)</sub>	I <sub>LD</sub> =10mA			0.5	V
Locking range				±3.125		%

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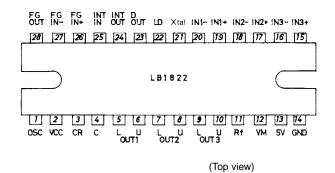
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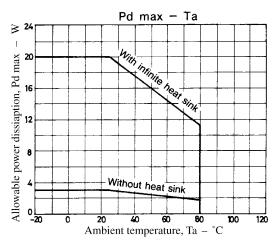
Parameter	Symbol	Conditions	Ratings			Unit
		Conditions	min	typ	max	Offic
[Start/Stop]	[Start/Stop]					
Operating voltage			0.4	0.5	0.6	V
[Crystal Oscillator]						
Precision of oscillating frequnecy		Referenced to indicated frequnecy	-500		500	ppm
Temperature coefficient				-3		ppm/°C
Drift in rotation speed				±0.01		%

## **Truth Table**

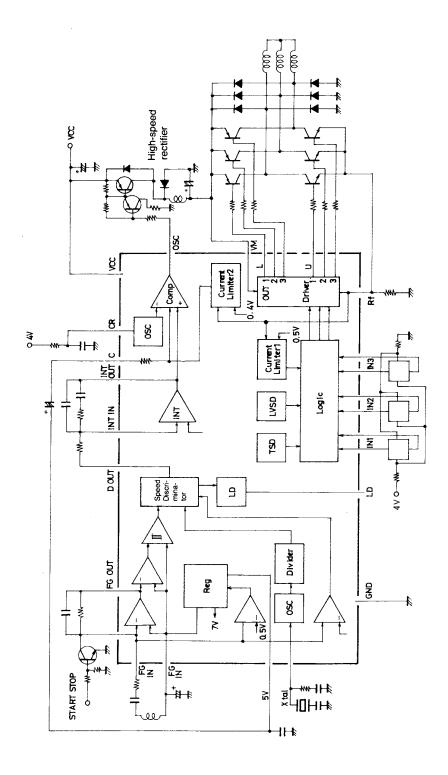
Item	Source Sink	Input			
	Source Sink	IN1	IN2	IN3	
1	OUT 3 → OUT 2	Н	Н	L	
2	OUT 3 → OUT 1	Н	L	L	
3	OUT 2 → OUT 3	L	L	Н	
4	OUT 1 → OUT 2	L	Н	L	
5	OUT 2 → OUT 1	Н	L	Н	
6	OUT 1 → OUT 3	L	Н	Н	

## **Pin Assignment**





## **Block Diagram**



## **Description of Terminal Function**

Pin Name	Pin No.	Description	
IN+ 1, IN- 1	19, 20	OUT1:Hall element input terminals for Phase 1.  "H" logic is the state when IN <sup>+</sup> > IN <sup>-</sup> .	
IN+ 2, IN- 2	17, 18	OUT2: Hall element input terminals for Phase 2.  "H" logic is the state when IN <sup>+</sup> > IN <sup>-</sup> .	
IN+ 3, IN-3	15, 16	OUT3: Hall element input terminals for Phase 3.  "H" logic is the state when IN <sup>+</sup> > IN <sup>-</sup> .	
OUT1	5, 6	Output terminals for Phase 1. Usource	
OUT2	7, 8	Output terminals for Phase 2. Lsink	
OUT3	9, 10	Output terminals for Phase 3.	
Vcc	2	Power supply for everything, except outputs.	
V <sub>M</sub>	12	Power supply for outputs.	
R <sub>f</sub>	11	Output current detection terminal. An R <sub>f</sub> is conented across this terminal and GND, and the output current is detectied as voltage.	
CR	3	Sets the oscillating frequency of the switching regulator.	
OSC	1	Outputs duty-controlled pulses. Open-collector output.	
INT. OUT	24	Integrator output terminal (speed control terminal).  Varies the switching regulator output votlage.	
INT. IN	25	Integrator input terminal.	
D. OUT	23	Speed discriminator output terminal.  Goes LOW when the specified speed is exceeded.	
С	4	Suppresses ripples in the motor current during operation of current limiter 2.	
LD	22	Lock detection terminal.  Goes LOW when the motor rotation speed is when the locking range.	
FG IN <sup>+</sup>	27 26	FG pulse input (Start/Stop control) terminal. FG pulse input (4V supply) terminal.	
FGOUT	28	FG amp output termianl.	
X' tal	21	Crystal oscillator terminal to which a crystal resonator is connected.	
5V	13	5V supply terminal.	

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